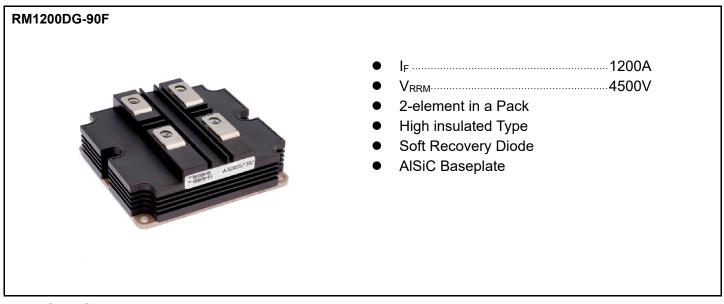


< HIGH VOLTAGE DIODE MODULES >

RM1200DG-90F

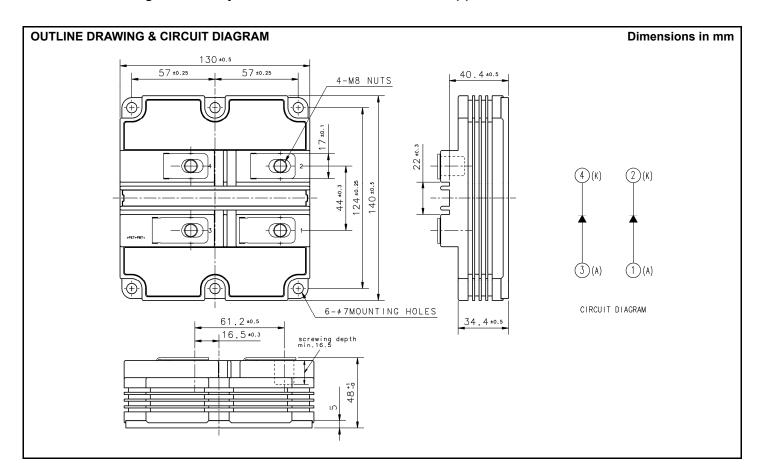
HIGH POWER SWITCHING USE INSULATED TYPE

High Voltage Diode Modules



APPLICATION

Traction drives, High Reliability Converters / Inverters, DC choppers



HIGH POWER SWITCHING USE INSULATED TYPE

MAXIMUM RATINGS

Symbol	Item	Conditions	Ratings	Unit	
M	Denetitive needs reverse veltage	T _j = -40+125°C	4500	V	
V_{RRM}	Repetitive peak reverse voltage	$T_j = -50$ °C	4400		
I _F	Forward current	DC, T _c = 65°C	1200	Α	
I _{FSM}	Surge forward current	T 405°0 t 40 ms Half sin a man V 0 V	9.8	kA	
I ² t	Surge current load integral	T_{j_start} = 125°C, t_p = 10 ms, Half-sine wave, V_R = 0 V	480	kA ² s	
P _{tot}	Maximum power dissipation	T _c = 25°C	6250	W	
V _{iso}	Isolation voltage	RMS, sinusoidal, f = 60 Hz, t = 1 min.	10200	V	
V _e	Partial discharge extinction voltage	RMS, sinusoidal, f = 60 Hz, Q _{PD} ≤ 10 pC	3500	V	
T_j	Junction temperature		− 50 ~ + 150	°C	
T_jop	Operating junction temperature		−50 ~ +125	°C	
T_{stg}	Storage temperature		− 55 ~ + 125	°C	

ELECTRICAL CHARACTERISTICS

Comple at	lk	Conditions		Limits			Unit	
Symbol	Item			Min	Тур	Max	Unit	
	Denetitive reverse surrent	\ \ -\\	T _j = 25°C	1	1	3.0	mA	
I _{RRM}	Repetitive reverse current	$V_{RM} = V_{RRM}$	T _j = 125°C	_	9.0		MA	
M	Familiand valtage	L = 4000 A	T _j = 25°C	-	2.55		V	
V_{FM}	Forward voltage	I _F = 1200 A	T _j = 125°C	_	2.85	3.45	V	
	Davis and a second at the second		T _j = 25°C	_	0.70	_		
t _{rr}	Reverse recovery time	V _{CC} = 2800 V	T _j = 125°C	_	0.90	_	μs	
	Poverse receivery current	I _F = 1200 A	T _j = 25°C	_	1050	_	Α	
Irr	Reverse recovery current		T _j = 125°C	_	1140	_	A	
Q _{rr}	Poverse receivery charge	$-d_i/d_t = 3900 \text{ A/}\mu\text{s} @ T_j = 25^{\circ}\text{C}$	T _j = 25°C	_	990			
Qrr	Reverse recovery charge	$-d_i/d_t = 3600 \text{ A/}\mu\text{s} @ T_i = 125^{\circ}\text{C}$	T _j = 125°C	-	1560		μC	
_	(Note 1)	L _s = 150 nH	T _j = 25°C	_	1.44	_		
E _{rec(10%)}	Reverse recovery energy (Note 1)		T _j = 125°C	_	2.25		J	
F	Deverse receivery energy	Inductive load	T _j = 25°C	_	1.65	_		
E _{rec}	Reverse recovery energy	Į .	T _j = 125°C	_	2.55		J	

THERMAL CHARACTERISTICS

Cumbal	Item	Conditions	Limits			Unit
Symbol	iteiii	Conditions	Min	Тур	Max	Offic
R _{th(j-c)}	Thermal resistance	Junction to Case (per 1/2 module)			20.0	K/kW
$R_{\text{th(c-s)}}$	Contact thermal resistance	Case to heat sink, λ_{grease} = 1 W/m k D _(c-s) = 100 µm (per 1/ 2 module)		16.0	_	K/kW

MECHANICAL CHARACTERISTICS

Cumbal	Symbol Item	Conditions	Limits			Linit
Symbol			Min	Тур	Max	Unit
M_t	Manustin a tanana	M8 : Main terminals screw	7.0	1	22.0	N·m
Ms	Mounting torque	M6 : Mounting screw	3.0	1	6.0	N·m
m	Mass		_	1.0	_	kg
CTI	Comparative tracking index		600	1		_
d _a	Clearance		26.0	1		mm
d _s	Creepage distance		56.0	1		mm
L _{PAK}	Parasitic stray inductance		1	44.0	1	nΗ
R _{AA'+KK'}	Internal lead resistance	$T_c = 25$ °C, 1/2 module	_	0.27		mΩ

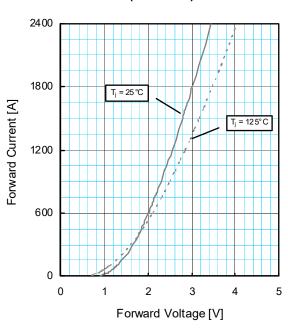
Note 1. Note 2.

 $E_{\rm rec(10\%)}$ are the integral of 0.1V_R x 0.1I_F x dt. Definition of all items is according to IEC 60747, unless otherwise specified.

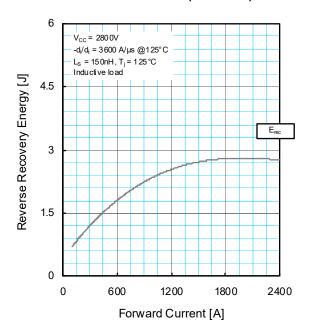
PERFORMANCE CURVES

INSULATED TYPE

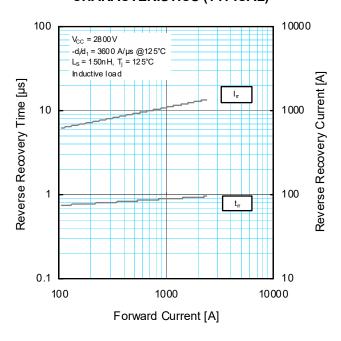
FORWARD CHARACTERISTICS (TYPICAL)



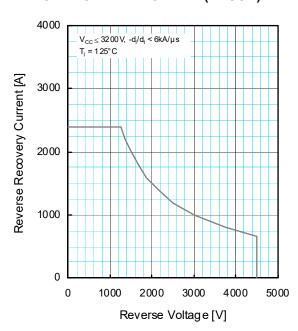
REVERSE RECOVERY ENERGY CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)

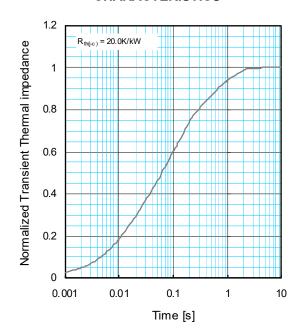


REVERSE RECOVERY SAFE OPERATING AREA (RRSOA)



PERFORMANCE CURVES

TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS



$$Z_{th(j-c)}(t) = \sum_{i=1}^{n} R_{i} \left\{ 1 - exp^{\left(-\frac{t}{\tau_{i}}\right)} \right\}$$

	1	2	3	4
R _i [K/kW]	0.0055	0.2360	0.4680	0.2905
t _i [sec]	0.0001	0.0131	0.0878	0.6247

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